2 Digital Electronics (IJW)

(a) Draw a diagram showing the structure of an n-channel MOSFET and describe how the Drain to Source current can be controlled. [4 marks]

(b) Draw the circuit diagram of a NOT gate that comprises an n-channel MOSFET and a resistor $R$. [2 marks]

(c) For the NOT gate in part (b), plot the relationship between the input voltage, $V_{in}$, and the output voltage, $V_{out}$. The power supply voltage, $V_{DD} = 10$ V, $R = 500$ $\Omega$, and the MOSFET has the characteristics given in the following figure. [6 marks]

(d) For the NOT gate in part (c), calculate the power dissipated by resistor $R$ when $V_{in} = 8$ V. [3 marks]

(e) (i) Describe how the power dissipated by resistor $R$ can be reduced. State any potential problems with your proposed solution. [3 marks]

(ii) Present a modified circuit for a NOT gate that eliminates the problem of static power dissipation in resistor $R$. [2 marks]